

Heisener.com

IPG20N04S412ATMA1

IPG20N04S412ATMA1 Information

Part Number IPG20N04S412ATMA1 Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2N-CH 8TDSON

8-PowerVDFN **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IPG20N04S412ATMA1 Specifications

	Report errors?
Supplier Device Package	PG-TDSON-8-4
Package / Case	8-PowerVDFN
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 175°C (TJ)
Power - Max	41W
Input Capacitance (Ciss) (Max) @ Vds	1470pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	18nC @ 10V
Vgs(th) (Max) @ Id	4V @ 15μA
Rds On (Max) @ Id, Vgs	12.2 mOhm @ 17A, 10V
Current - Continuous Drain (Id) @ 25°C	20A
Drain to Source Voltage (Vdss)	40V
FET Feature	Standard
FET Type	2 N-Channel (Dual)
Series	Automotive, AEC-Q101, OptiMOS?
Package	8-PowerVDFN
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Manufacturer	Infineon Technologies
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IPG20N04S412ATMA1 Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IPG20N04S412ATMA1 Payment Methods



















IPG20N04S412ATMA1 Shipping Methods













If you have any question about IPG20N04S412ATMA1, please do not hesitate to contact us!

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